

SANYO

No.2157A

LA4580M

Monolithic Linear IC

2-CHANNEL PREAMP + POWER AMP FOR
3V HEADPHONE USE

The LA4580M is a single-chip pre/power amp IC designed for 3V auto reverse stereo headphone use.

Features

- . 2-channel IC containing preamplifiers and power amplifiers on a single chip.
- . On-chip electronic switch for forward/reverse select
(Time required for forward/reverse select can be controlled by an external capacitor.)
- . On-chip LED driver
- . 20-pin MFP package

Maximum Ratings at Ta=25°C

| | | unit |
|-----------------------------|---------------------|----------------|
| Maximum Supply Voltage | V _{CC} max | 4.5 V |
| Allowable Power Dissipation | P _d max | 400 mW |
| Operating Temperature | T _{opg} | -20 to +75 °C |
| Storage Temperature | T _{stg} | -40 to +125 °C |

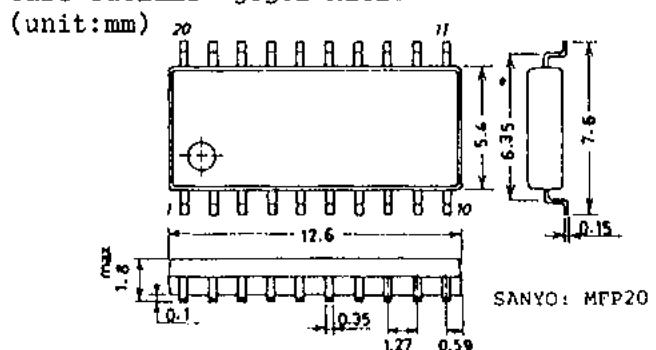
Operating Conditions at Ta=25°C

| | | unit |
|-----------------------------|--------------------|--------------|
| Recommended Supply Voltage | V _{CC} | 3 V |
| Operating Voltage Range | V _{CC} op | 1.8 to 3.6 V |
| Recommended Load Resistance | R _L | 16 to 32 ohm |

Operating Characteristics at Ta=25°C, V_{CC}=3V, f=1kHz

| Preamp: R _L =10kohms | | min | typ | max | unit |
|---------------------------------|-------------------|---|------|------|------|
| Voltage Gain | V _{GO} | Open loop | 75 | 86 | dB |
| Voltage Gain | V _G | Closed loop, V _O =0.2V | 41.5 | | dB |
| Maximum Output Voltage | V _O | THD=1% | 0.35 | 0.45 | V |
| Total Harmonic Distortion | THD | V _O =0.2V | 0.06 | 0.2 | % |
| Ripple Rejection | R _r | f _r =100Hz, R _g =2.2kohms | 40 | 50 | dB |
| Equivalent Input Noise Voltage | V _{NI} | V _{CCR} =-10dBm | | | |
| F/R Crosstalk | CT _{F/R} | R _g =2.2kohms, B.P.F.=20Hz to 20kHz | 1.0 | 2.0 | uV |
| | | R _g =2.2kohms, V _O =-3dBm | 60 | 70 | dB |

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Case Outline 3036B-M20IC

The application circuit diagrams and circuit constants herein are included as an example and provide no guarantee for designing equipment to be mass produced. The information herein is believed to be accurate and reliable. However, no responsibility is assumed by SANYO for its use; nor for any infringements of patents or other rights of third parties which may result from its use.

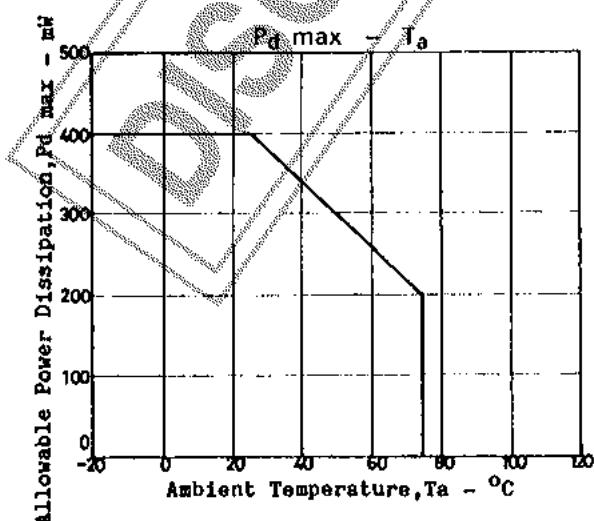
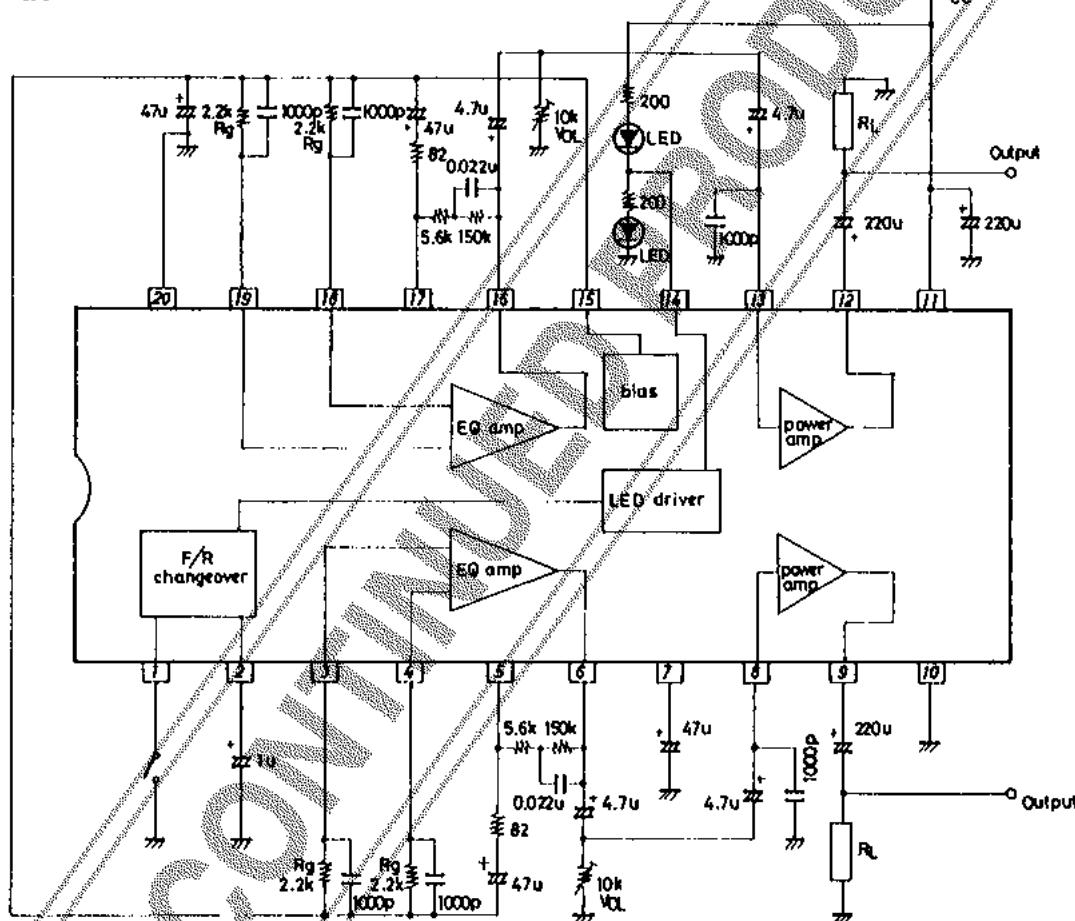
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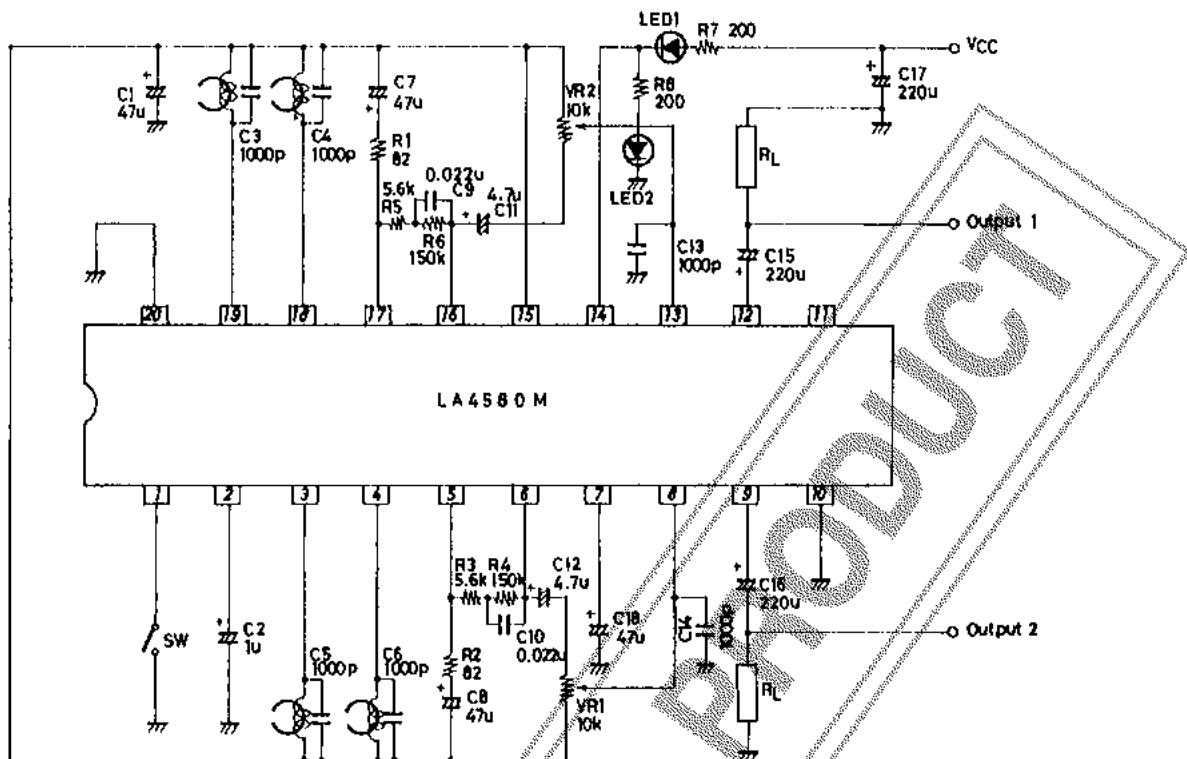
| | | | | | |
|--|------------------------------------|---|-----|-----|------|
| Power Amp: $R_L = 32\text{ohms}$ (pure resistance) | | min | typ | max | unit |
| Output Power | Po1 THD=10%, $R_L = 16\text{ohms}$ | 28 | 40 | | mW |
| | Po2 THD=10%, $R_L = 32\text{ohms}$ | 15 | 20 | | mW |
| Voltage Gain | VG $V_o = 0.18V$ | 26 | 29 | 32 | dB |
| Total Harmonic Distortion | THD Po=1mW(0.18V) | | 0.2 | 1.0 | % |
| Input Resistance | r_i | 22 | 30 | 38 | kohm |
| Output Noise Voltage | V_{NO} | Rg=0, B.P.F.=20Hz to 20kHz | 21 | 32 | uV |
| Ripple Rejection | Rr | f _r =100Hz, Rg=0, V _{CCr} =-10dBm | 40 | 50 | dB |
| Crosstalk between Channels | CT _{CH} | Rg=0, $V_o = 0.55V$ | 30 | 37 | dB |
| Pre+Power Amp | | | | | |
| Quiescent Current | I _{Q00} | EQ+Power | 9 | 16 | mA |
| R/L Crosstalk | CT _{CH} | Rg=2.2kohms, $V_o = -3\text{dBm}$ | 30 | 36 | dB |

Test Circuit

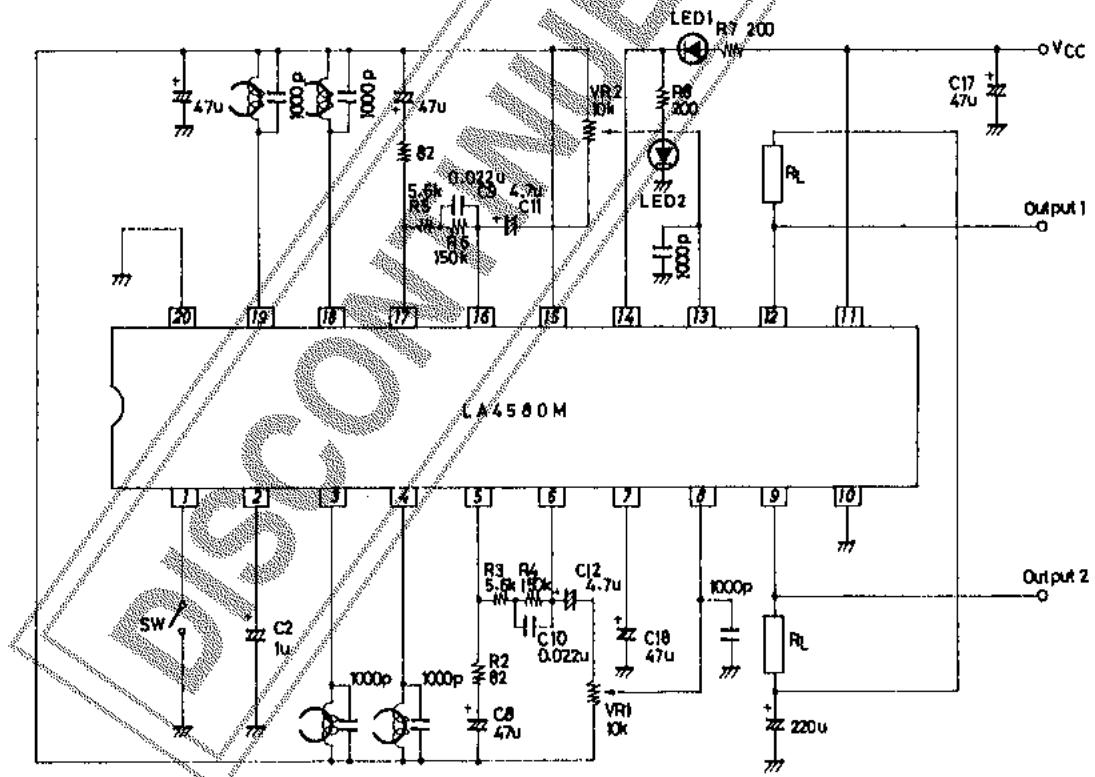


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Sample Application Circuit (1): Power input capacitor method

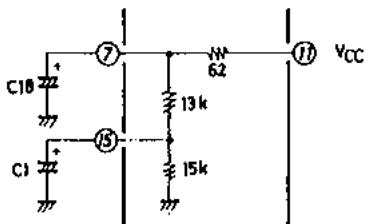


Sample Application Circuit (2): Power output capacitor common method



Description of External Parts [Power input capacitor method]

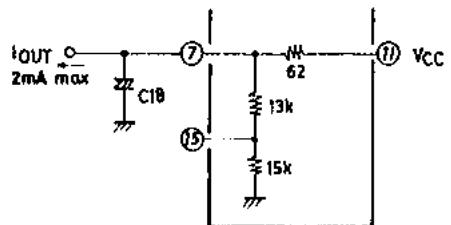
C1: Electrolytic capacitor



Connected to virtual GND reference voltage generation pin 15. The capacitor value is 33uF or greater. The C1 is so made as to be charged rapidly from GND potential to approximately 0.7V.

$$V_{15} = \frac{1}{2} V_{CC}$$

C18: Electrolytic capacitor,



Used for ripple filter and connected to the preamplifiers and bias circuit. The capacitor value is 47uF or greater. Current can be drawn from pin 7, but it should be noted that current draw from pin 7 causes an increase in voltage drop across pins 11 and 7, causing the voltage on pin 15 to drop and the power amp output power to drop.

$$I_{OUT} = 2mA \text{ max}$$

C2: Used to set F/R switching time t . The capacitor value of 1uF gives switching time t of approximately 0.16 second. Switching time t is increased by approximately 0.16 second with every additional 1uF of capacitor value.

(Refer to F/R Switching Time - Timing Capacitor Characteristic.)

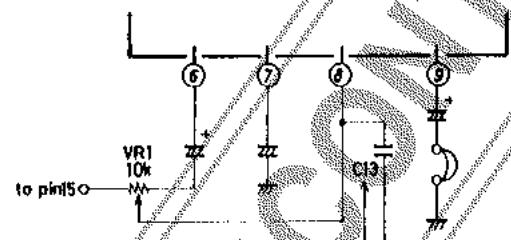
C3,C4,C5,C6: Used to prevent external noise from mixing in. The capacitor value is fixed according to the frequency characteristic of the playback head.

C7,C8: Negative feedback capacitor. 100uF or less. The lower limit is determined by the low cutoff frequency.

C9,C10: Used to determine the playback equalizer characteristics.

C11,C12: Preamp output capacitor. We recommend using a capacitor of 4.7uF. 1 to 10uF.

C13,C14: Used to prevent radiation and power amp oscillation from occurring.



We recommend using a capacitor of 1000pF. One plate of the C13 and C14 may be connected to virtual GND pin 15 or preamp GND pin 20 according to your intended printed circuit pattern so that the LA4580M exhibits better characteristics.

Connect to pin 15 or pin 20.

C15,C16: Power amp output capacitor. We recommend using a capacitor of 220uF.

C17: Power line capacitor. We recommend using a capacitor of 220uF.

R1,R2: Closed-loop gain setting resistor. $R1=R2=82\text{ohms}$ gives a gain of 41dB/1kHz.

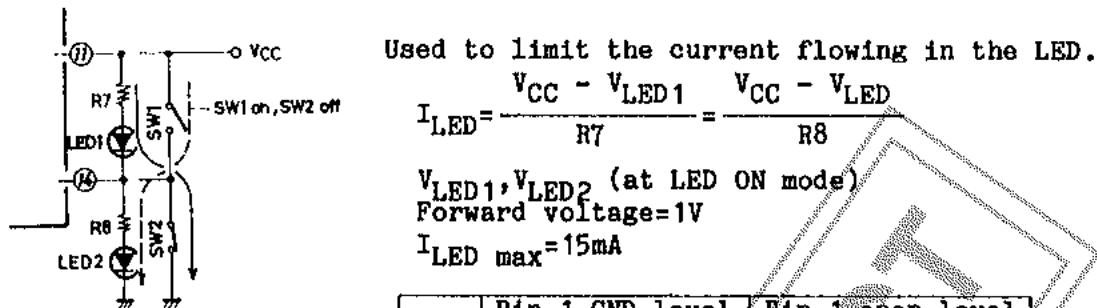
R3,R5: Used to determine the playback equalizer amp characteristics.

R4,R6: Used to determine the playback equalizer characteristics. Since R3,R4 (or R5,R6) are not only used to determine the frequency characteristic but also used as DC feedback resistor, do not connect a capacitor in series to block DC components. It should be noted that an increase in R3,R4 (or R5,R6) may cause an increase in output DC offset of the playback preamp, increasing the noise that is generated at the time of FWD/REV selection.

$$R3+R4 \text{ (or } R5+R6\text{)} = 500\text{kohms max.}$$

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R7,R8: LED current limiting resistor



When the LEDs are not used, pin 14 may be left open.

| | Pin 1 GND level | Pin 1 open level |
|-----|-----------------|------------------|
| SW1 | on | off |
| SW2 | off | on |

Oscillation of power amp (When a headphone is mounted)

If oscillation occurs with a headphone mounted, connect a capacitor of 22000pF across the headphone.

F/R selection

The preamp input selection can be made by bringing pin 1 to open state, GND level.

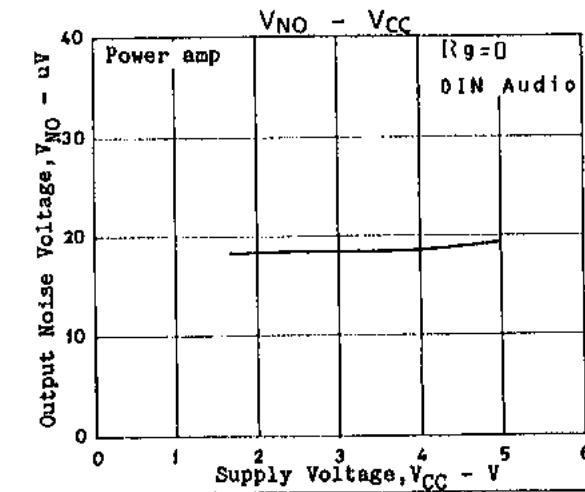
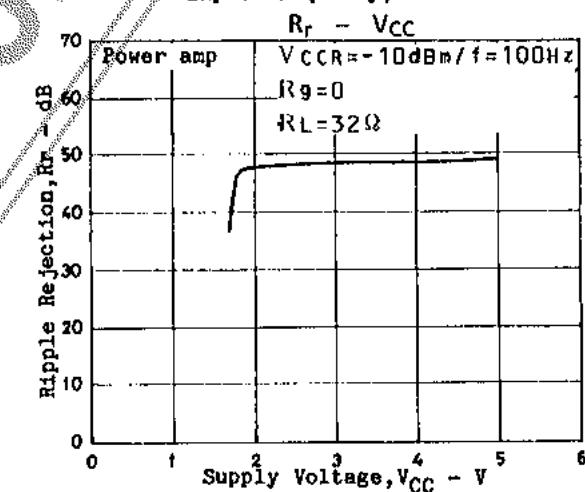
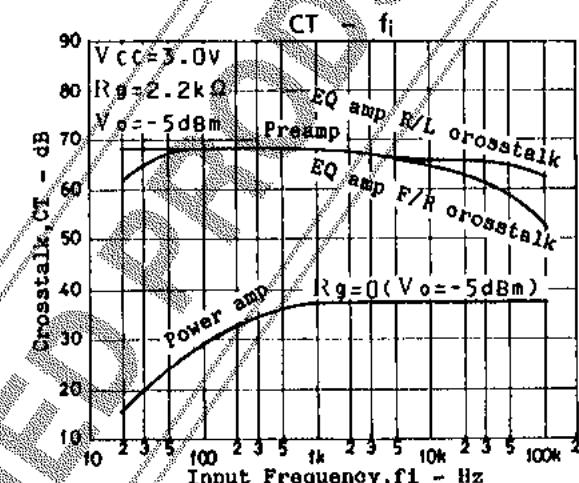
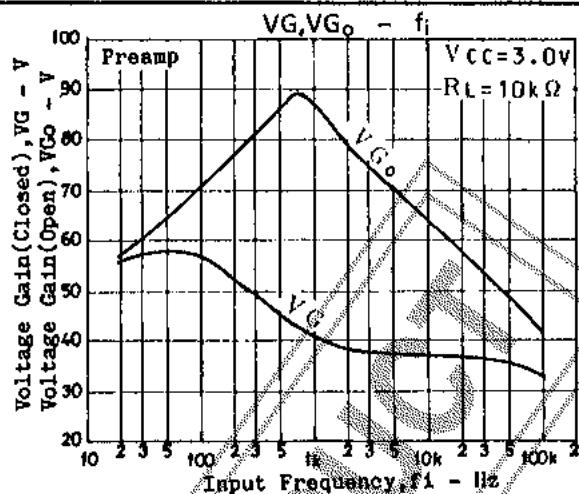
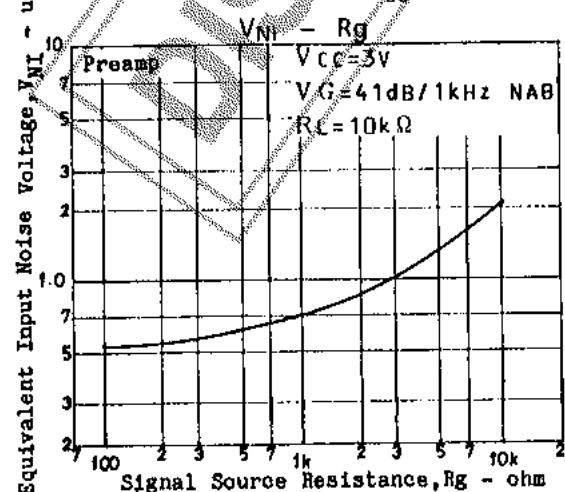
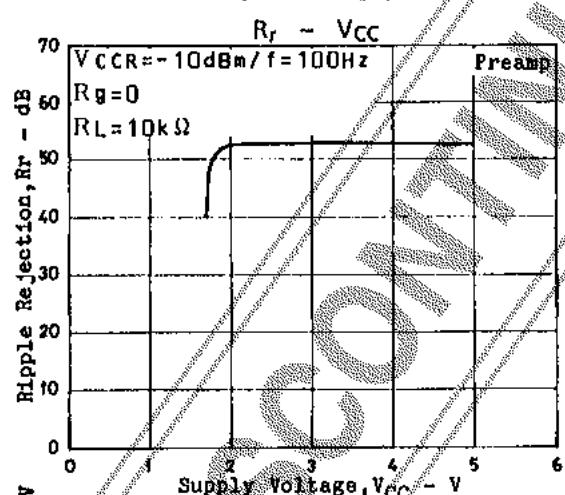
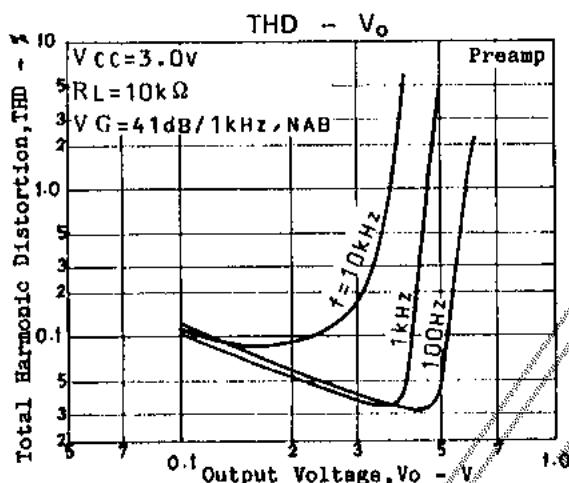
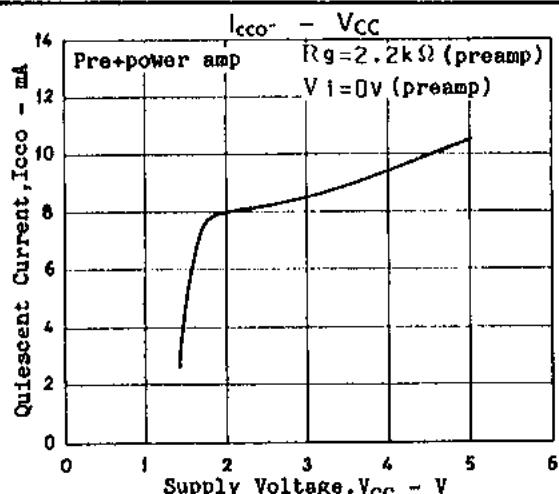
Pin ① open Pins ③, ⑨ ON
Pin ① GND Pins ④, ⑩ ON

When F/R selection is not made it is recommended that both of pins ① ② are left open. In this case, pins ③, ⑨ only are used as input pins.

Bias voltage on each pin of LA4580M

| Pin No. | V _{CC} =1.8V | V _{CC} =3.0V | V _{CC} =4.5V |
|---------|-----------------------|-----------------------|-----------------------|
| 1 | 0-1.315 | 0-1.322 | 0-1.322 |
| 2 | 1.331-0.01 | 1.328-0.01 | 1.329-0.011 |
| 3 | 0.843 | 1.441 | 2.119 |
| 4 | 0.844 | 1.441 | 2.123 |
| 5 | 0.859 | 1.445 | 2.156 |
| 6 | 0.941 | 1.515 | 2.219 |
| 7 | 1.649 | 2.799 | 4.237 |
| 8 | 0.791 | 1.333 | 2.016 |
| 9 | 0.466 | 0.947 | 1.485 |
| 10 | G | G | G |
| 11 | 1.80 | 3.00 | 4.50 |
| 12 | 0.472 | 1.002 | 1.639 |
| 13 | 0.787 | 1.307 | 1.960 |
| 14 | 0.010 | 0.125 | 0.266 |
| 15 | 0.847 | 1.424 | 2.148 |
| 16 | 0.910 | 1.488 | 2.189 |
| 17 | 0.851 | 1.432 | 2.135 |
| 18 | 0.850 | 1.427 | 2.120 |
| 19 | 0.848 | 1.423 | 2.123 |
| 20 | G | G | G |

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